imall

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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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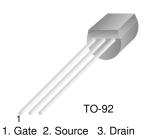
September 2007



2N5951 N-Channel RF Amplifier

• This device is designed primarily for electronic switching applications such as low on resistance analog switching.

• Sourced from process 50.



Absolute Maximum Ratings* Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{DG}	Drain-Gate Voltage	30	V
V _{GS}	Gate-Source Voltage	-30	V
I _{GF}	Forward Gate Current	10	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ 150	°C

* This ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These rating are based on a maximum junction temperature of 150 degrees C.

2) These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics $\ensuremath{\mathsf{T}}_a\ensuremath{=}25\ensuremath{^\circ}\ensuremath{\mathsf{C}}$ unless otherwise noted

Symbol	Parameter	Max.	Units
P _D Total Device Dissipation		350	mW
	Derate above 25°C	2.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W
R _{0JA}	Thermal Resistance, Junction to Ambient	357	°C/W

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Chara	storistics				
V _{(BR)GSS}	Gate-Source Breakdown Voltage	I _G = 1.0μA, V _{DS} = 0	-30		V
I _{GSS}	Gate Reverse Current	$V_{GS} = 15V, V_{DS} = 0, T = 25^{\circ}C$ T = 100°C		-1.0 -200	nA
V _{GS(off)}	Gate-Source Cut-off Voltage	V _{DS} = 15V, I _D = 100nA	-2	-5	V
V _{GS}	Gate-Source Forward Voltage	V _{DS} = 15V, I _D = 700μA	-1.3	-4.5	V
*I _{DSS} Rps(on)	Zero-Gate Voltage Drain Current * Drain-Source On Resistance	$V_{DS} = 15V, V_{GS} = 0$ $I_{D} = 400 \mu A, f = 1.0 kHz$	7	13 250	mA Ω
RDS(on)		$I_{D} = 400 \mu A, f = 1.0 kHz$		250	Ω
Goss	nal Characteristics Common- Source Output Conductance	V _{DS} = 15V, V _{GS} = 0V, f = 1.0kHz		75	μ/Ω
gos	Output Conductance	$V_{DS} = 15V, V_{GS} = 0V, f = 100MHz$		100	μ/Ω
gis	Input Conductance	V _{DS} = 15V, V _{GS} = 0V, f = 100MHz		250	μ/Ω
	Input Capacitance	V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz		6	pF
Ciss	Description Transform Operation	V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz		2	pF
	Reverse Transfer Capacitance				
Ciss Crss en	Equivalent Short-Circuit Input Noise Voltage	$V_{DS} = 15V, V_{GS} = 0V, f = 1.0kHz$		100	nV

* Pulse Test: Pulse Width \leq 300µs, Duty Cycle = 2%



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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.	
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